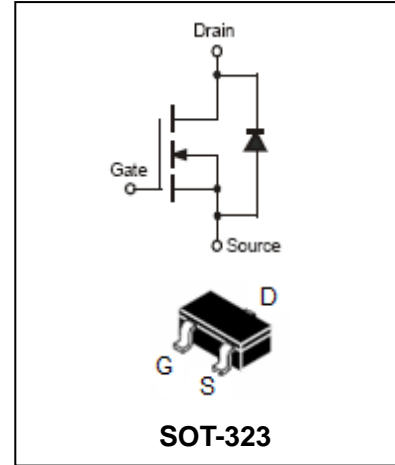




FEATURES

- Low on-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage



ORDERING INFORMATION

Type No.	Marking	Package Code
BSS138W	K38	SOT-323

MAXIMUM RATING @ Ta=25°C unless otherwise specified

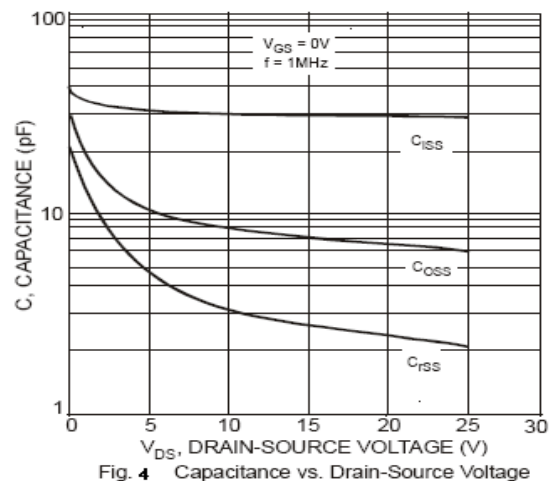
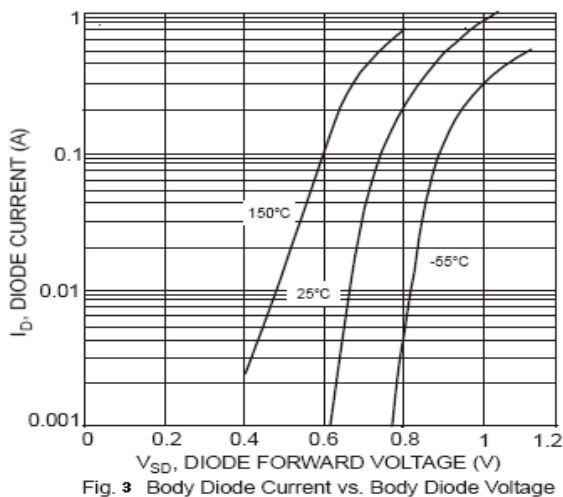
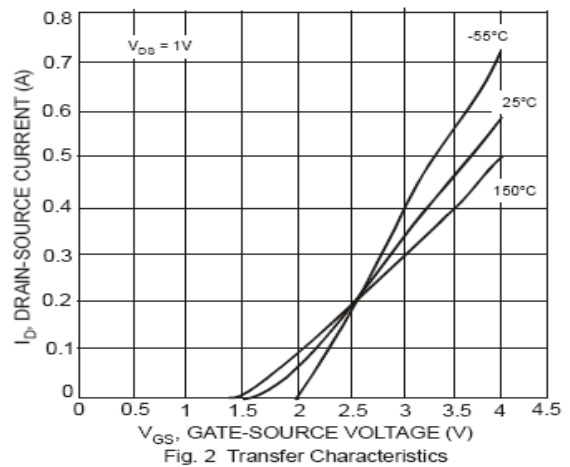
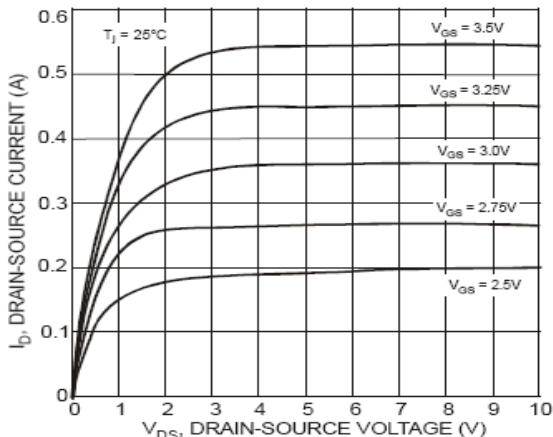
Symbol	Parameter	Value	Units
V_{DSS}	Drain-Source voltage	50	V
V_{DGR}	Drain-Gate voltage $R_{GS} \leq 20K \Omega$	50	V
V_{GSS}	Gate-Source Voltage	± 20	V
I_D	Drain current -continuous	200	mA
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	625	°C/W
T_J, T_{stg}	Junction and Storage Temperature	-55 to +150	°C



ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Gate leakage current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$			± 1	μA
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	50	75		V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	1.2	1.5	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=50V, V_{GS}=0V$			0.5	μA
Drain-source on-state resistance	$R_{DS(on)}$	$I_D=0.22A, V_{GS}=10V$		1.4	3.5	Ω
Forward transfer admittance	g_{FS}	$V_{DS}=25V, I_D=0.2A, f=1MHz$	100			mS
Input capacitance	C_{ISS}	$V_{DS}=10V, V_{GS}=0V, f=1.0MHz$			50	pF
Output capacitance	C_{OSS}				25	
Reverse transfer capacitance	C_{RSS}				8	
Turn-On Delay Time	$t_{D(ON)}$	$V_{DD}=30V, I_D=0.2A,$ $R_{GEN}=50\Omega$			20	ns
Turn-Off Delay Time	$t_{D(OFF)}$				20	ns

TYPICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

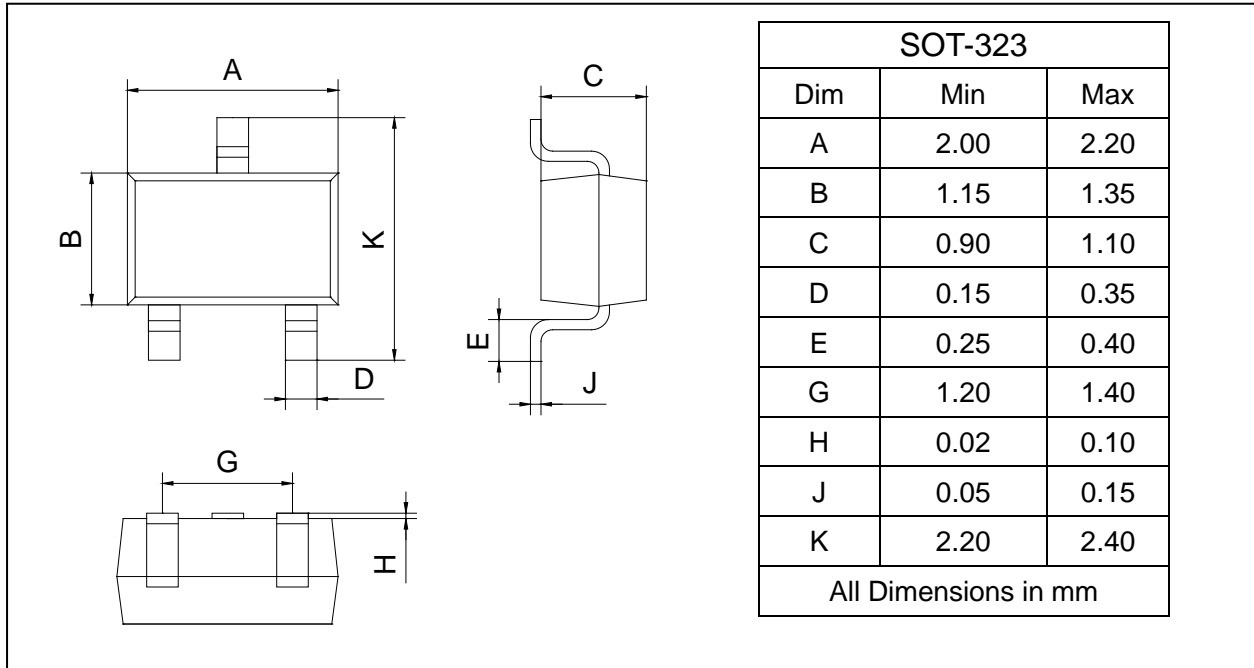




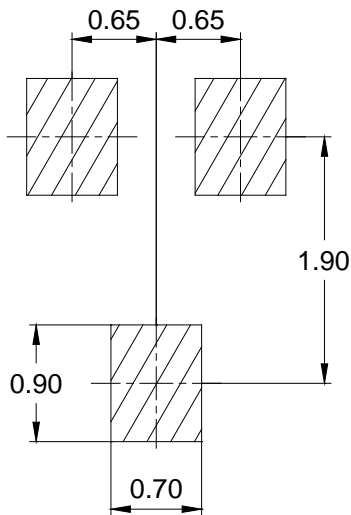
PACKAGE OUTLINE

Plastic surface mounted package

SOT-323



SOLDERING FOOTPRINT



Unit: mm

PACKAGE INFORMATION

Device	Package	Shipping
BSS138W	SOT-323	3000/Tape&Reel